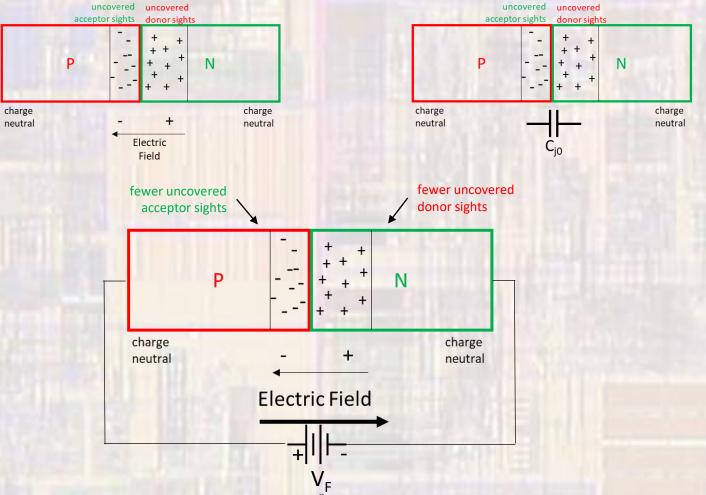
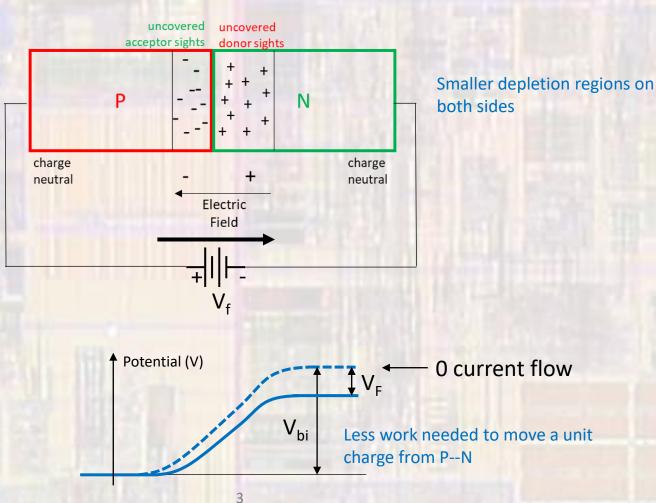
Last updated 2/10/22

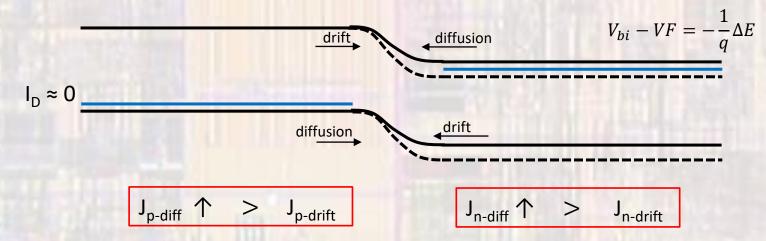
- Forward bias
 - P side at a higher voltage than the N side



- Forward Bias
 - P side at a higher voltage than the N side

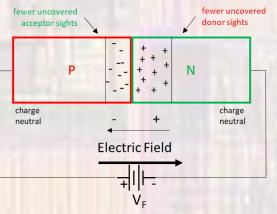


- Forward Bias
 - The forward bias shifts the energy bands relative to the P and N side
 - No impact on the drift current
 - Increases the number of carriers that have sufficient energy to diffuse (exponentially)



- Resulting net current can be large and positive $(P \rightarrow N)$
 - additional forward bias leads to exponential increases in current

• Forward Bias – Junction Capacitance



smaller depletion region (W) → additional capacitance

Note: this is a Majority Carrier phenomena and can be very fast → small capacitance

$$C_j = C_{j0} \left(1 - \frac{V_A}{V_{bi}} \right)^{-1/2}$$

$$V_A = V_F$$

Small voltage changes \rightarrow changes in diffusion charge

Note: this is a Minority Carrier phenomena and is relatively slow → large (relative) capacitance

© ti

 $C_D \approx e^{V_A/_{V_T}}$ $V_{\Delta} = V_{F}$

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